NSN 5961-01-325-4452

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-325-4452 **Inclosure Material:** Metal **Overall Length:** Between 0.205 inches and 0.225 inches **Terminal Length:** Between 0.060 inches and 0.064 inches **Overall Diameter:** Between 0.119 inches and 0.127 inches **Function For Which Designed:** Switching **Mounting Method: Terminal Features Provided:** Burn in and hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 500.0 breakdown voltage, dc **Current Rating Per Characteristic:** 250.00 nanoamperes forward current, average peak **Capacitance Rating In Picofarads:** 0.9 **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Precious Material And Location:** Terminal surfaces gold **Precious Material:** Gold **Terminal Type And Quantity:** 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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